THE DATASHEET OF

AD8676ARMZ-REEL

www.win-source.net 0086-755-83957316

Ultraprecision, 36 V, 2.8 nV/√Hz Dual Rail-to-Rail Output Op Amp

Data Sheet

AD8676

FEATURES

Very low voltage noise 2.8 nV/√Hz @ 1 kHz
Rail-to-rail output swing
Low input bias current: 2 nA maximum
Very low offset voltage: 12 µV typical
Low input offset drift: 0.6 µV/°C maximum
Very high gain: 120 dB
Wide bandwidth: 10 MHz typical
±5 V to ±18 V operation

APPLICATIONS

Precision instrumentation
PLL filters
Laser diode control loops
Strain gage amplifiers
Medical instrumentation
Thermocouple amplifiers

PIN CONFIGURATIONS

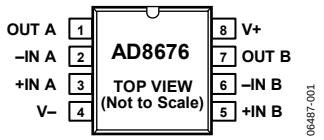

Figure 1. 8-Lead SOIC_N (R-8)

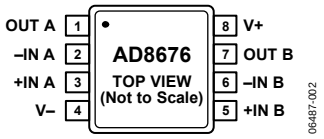

Figure 2. 8-Lead MSOP (RM-8)

GENERAL DESCRIPTION

The AD8676 precision operational amplifier offers ultralow offset, drift, and voltage noise combined with very low input bias currents over the full operating temperature range. The AD8676 is a precision, wide bandwidth op amp featuring rail-to-rail output swings and very low noise. Operation is fully specified from ±5 V to ±15 V.

The AD8676 features a rail-to-rail output like that of the OP184, but with wide bandwidth and even lower voltage noise, combined with the precision and low power consumption like that of the industry-standard OP07 amplifier. Unlike other low noise, rail-to-rail op amps, the AD8676 has very low input bias current and low input current noise.

With typical offset voltage of only 12 µV, offset drift of 0.2 µV/°C, and noise of only 0.10 µV p-p (0.1 Hz to 10 Hz), the AD8676 is perfectly suited for applications where large error sources cannot be tolerated. Precision instrumentation, PLL and other precision filter circuits, position and pressure sensors, medical instrumentation, and strain gage amplifiers benefit greatly from the very low noise, low input bias current, and wide bandwidth. Many systems can take advantage of the low noise, dc precision, and rail-to-rail output swing provided by the AD8676 to maximize SNR and dynamic range.

The smaller packages and low power consumption afforded by the AD8676 allow maximum channel density or minimum board size for space-critical equipment.

The AD8676 is specified for the extended industrial temperature range (−40°C to +125°C). The AD8676 is available in the 8-lead MSOP, and the popular 8-lead, narrow SOIC; both of which are lead-free packages. MSOP packaged devices are only available in tape and reel format.

For the single version of this ultraprecision, rail-to-rail op amp, see the AD8675 data sheet.

The AD8675 and AD8676 are members of a growing series of low noise op amps offered by Analog Devices, Inc.

Table 1. Voltage Noise

Package	0.9 nV	1.1 nV	1.8 nV	2.8 nV	3.8 nV
Single	AD797	AD8597	ADA4004-1	AD8675	AD8671
Dual		AD8599	ADA4004-2	AD8676	AD8672
Quad			ADA4004-4		AD8674

Rev. C

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TABLE OF CONTENTS

Features 1
Applications 1
Pin Configurations 1
General Description 1
Revision History 2
Specifications 3
Electrical Specifications 3
Absolute Maximum Ratings 5
Thermal Resistance 5
Power Sequencing 5
ESD Caution 5
Typical Performance Characteristics 6
Outline Dimensions 11
Ordering Guide 11

REVISION HISTORY

8/11—Rev. B to Rev. C

Change to Y-Axis Label, Figure 9 7

11/09—Rev. A to Rev. B

Changes to General Description Section 1
Added Table 1; Renumbered Sequentially 1
Updated Outline Dimensions 11
Changes to Ordering Guide 11

4/08—Rev. 0 to Rev. A

Changes to Table 1 3
Changes to Table 2 4
Changes to Figure 6, Figure 7, Figure 8 6
Changes to Figure 9 through Figure 12 7
Changes to Figure 21, Figure 22, and Figure 25 9
Added Figure 26, Renumbered Sequentially 9
Changes to Figure 27 10
Added Figure 28, Renumbered Sequentially 10

10/06—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

V_S = ±5.0 V, V_{CM} = 0 V, V_O = 0 V, T_A = +25°C, unless otherwise specified.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}					
B Grade (SOIC)				12	50	µV
B Grade (MSOP)					60	µV
A Grade (SOIC, MSOP)					100	µV
Offset Voltage	V_{OS}	−40°C ≤ T_A ≤ +125°C				
B Grade (SOIC, MSOP)				15	160	µV
A Grade (SOIC, MSOP)					250	µV
Input Bias Current	I_B		−2		+2	nA
		−40°C ≤ T_A ≤ +125°C	−5.5		+5.5	nA
Input Offset Current	I_{OS}		−1		+1	nA
		−40°C ≤ T_A ≤ +125°C	−2.8		+2.8	nA
Input Voltage Range			−3.0		+3.0	V
Common-Mode Rejection Ratio	CMRR	V_{CM} = −3.0 V to +3.0 V	105	130		dB
		−40°C ≤ T_A ≤ +125°C	105			dB
Open-Loop Gain	A_{VO}	R_L = 2 kΩ to ground,	120	126		dB
		V_O = −3.5 V to +3.5 V				
		−40°C ≤ T_A ≤ +125°C	117			dB
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C ≤ T_A ≤ +125°C		0.2	0.6	µV/°C
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_L = 10 kΩ to ground	+4.90	+4.95		V
		−40°C ≤ T_A ≤ +125°C	+4.85			V
		R_L = 2 kΩ to ground	+4.80	+4.89		V
		−40°C ≤ T_A ≤ +125°C	+4.75			V
Output Voltage Low	V_{OL}	R_L = 10 kΩ to ground		−4.98	−4.90	V
		−40°C ≤ T_A ≤ +125°C			−4.85	V
		R_L = 2 kΩ to ground		−4.91	−4.86	V
		−40°C ≤ T_A ≤ +125°C			−4.82	V
Short-Circuit Limit	I_{SC}			+40		mA
Output Current	I_O			±20		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_S = ±5.0 V to ±15.0 V	106	120		dB
		−40°C ≤ T_A ≤ +125°C	106	120		dB
Supply Current/Amplifier	I_{SY}	V_O = 0 V		2.5	3.2	mA
		−40°C ≤ T_A ≤ +125°C			3.8	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R_L = 2 kΩ		2.5		V/µs
Gain Bandwidth Product	GBP			10		MHz
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.1		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		2.8		nV/√Hz
Current Noise Density	i_n	f = 10 Hz		0.3		pA/√Hz

V_S = ±15 V, V_{CM} = 0 V, V_O = 0 V, T_A = +25°C, unless otherwise specified.

Table 3.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}					
B Grade (SOIC)				12	50	µV
B Grade (MSOP)					60	µV
A Grade (SOIC, MSOP)					100	µV
Offset Voltage	V_{OS}	−40°C ≤ T_A ≤ +125°C				
B Grade (SOIC, MSOP)				15	160	µV
A Grade (SOIC, MSOP)					250	µV
Input Bias Current	I_B		−2		+2	nA
		−40°C ≤ T_A ≤ +125°C	−4.5		+4.5	nA
Input Offset Current	I_{OS}		−1		+1	nA
		−40°C ≤ T_A ≤ +125°C	−2.8		+2.8	nA
Input Voltage Range			−12.5		+12.5	V
Common-Mode Rejection Ratio	CMRR	V_{CM} = −12.5 V to +12.5 V	111	130		dB
		−40°C ≤ T_A ≤ +125°C	107	130		dB
Open-Loop Gain	A_{VO}	R_L = 2 kΩ to ground,	123	132		dB
		V_O = −13.5 V to +13.5 V				
		−40°C ≤ T_A ≤ +125°C	117			dB
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C ≤ T_A ≤ +125°C		0.2	0.6	µV/°C
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_L = 10 kΩ to ground	+14.85	+14.92		V
		−40°C ≤ T_A ≤ +125°C	+14.80			V
		R_L = 2 kΩ to ground	+14.60	+14.75		V
		−40°C ≤ T_A ≤ +125°C	+14.40			V
Output Voltage Low	V_{OL}	R_L = 10 kΩ to ground		−14.96	−14.94	V
		−40°C ≤ T_A ≤ +125°C			−14.90	V
		R_L = 2 kΩ to ground		−14.85	−14.75	V
		−40°C ≤ T_A ≤ +125°C			−14.60	V
Short-Circuit Limit	I_{SC}			+40		mA
Output Current	I_O			±20		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_S = ±5.0 V to ±15.0 V	106	120		dB
		−40°C ≤ T_A ≤ +125°C	106			dB
Supply Current/Amplifier	I_{SY}	V_O = 0 V		2.7	3.4	mA
		−40°C ≤ T_A ≤ +125°C			4.2	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R_L =10 kΩ		2.5		V/µs
Gain Bandwidth Product	GBP			10		MHz
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.1		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		2.8		nV/√Hz
Current Noise Density	i_n	f = 10 Hz		0.3		pA/√Hz

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
Supply Voltage	±18 V
Input Voltage	±V supply
Differential Input Voltage	±0.7 V
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	
RM, R Packages	−65°C to +150°C
Operating Temperature Range	−40°C to +125°C
Junction Temperature Range	
RM, R Packages	−65°C to +150°C
Lead Temperature Range (Soldering, 10 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 5. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-Lead MSOP (RM)	210	45	°C/W
8-Lead SOIC_N (R)	158	43	°C/W

POWER SEQUENCING

The op amp supplies must be established simultaneously with, or before, any input signals are applied. If this is not possible, the input current must be limited to 10 mA.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

±15 V and ±5 V, T_A = 25°C, unless otherwise specified.

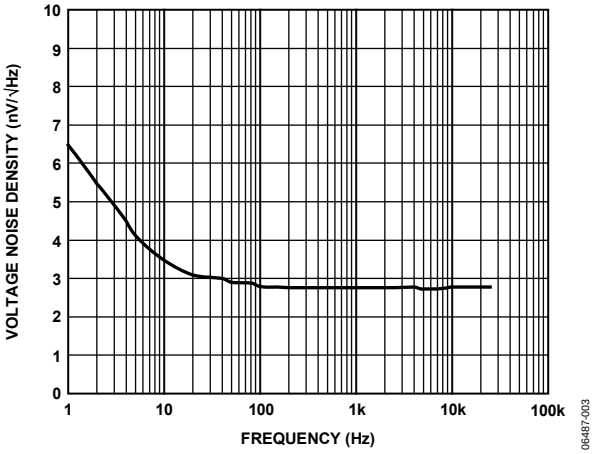

Figure 3. Voltage Noise Density vs. Frequency

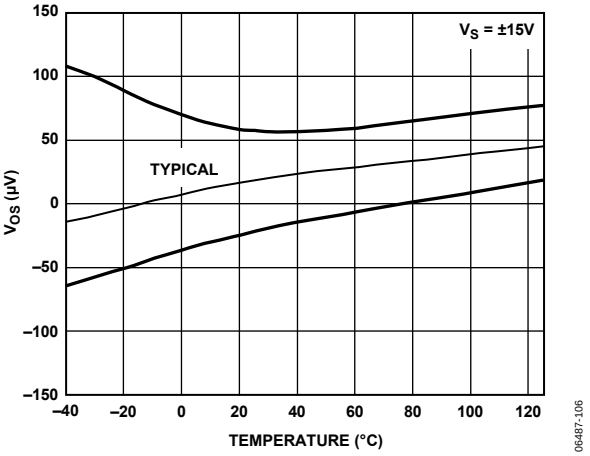

Figure 6. Offset Voltage vs. Temperature

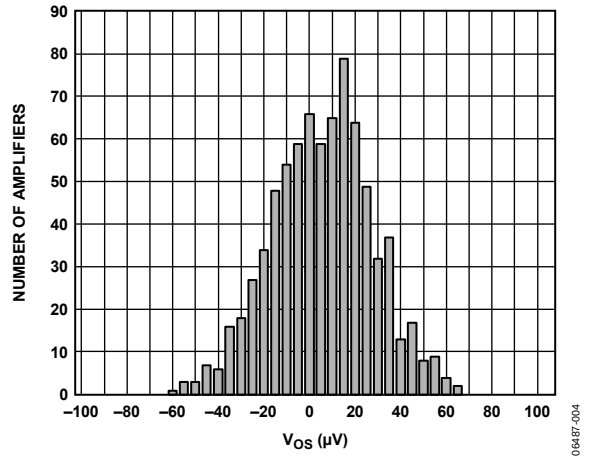

Figure 4. Input Offset Voltage Distribution

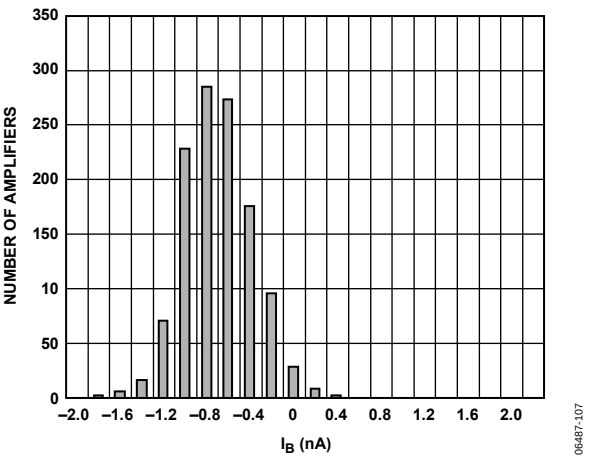

Figure 7. Input Bias Current, V_{SY} = ±15 V

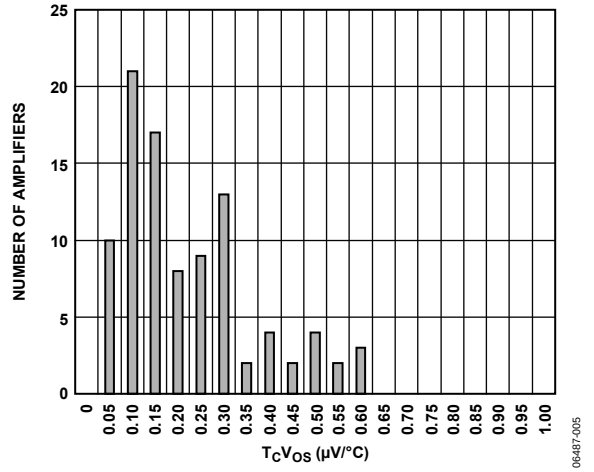

Figure 5. T_CV_{OS} Distribution

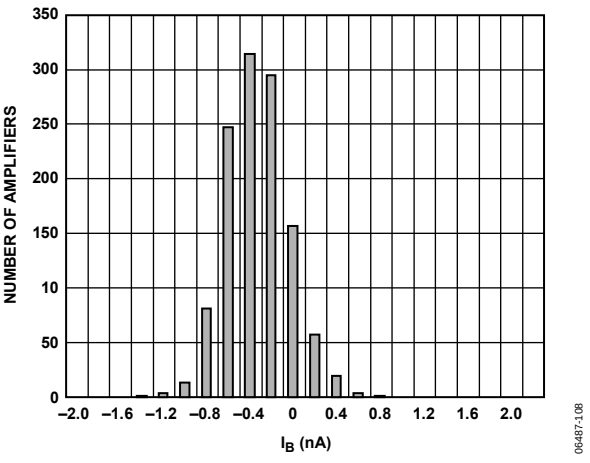

Figure 8. Input Bias Current, V_{SY} = ±5 V

±15 V and ±5 V, T_A = 25°C, unless otherwise specified.

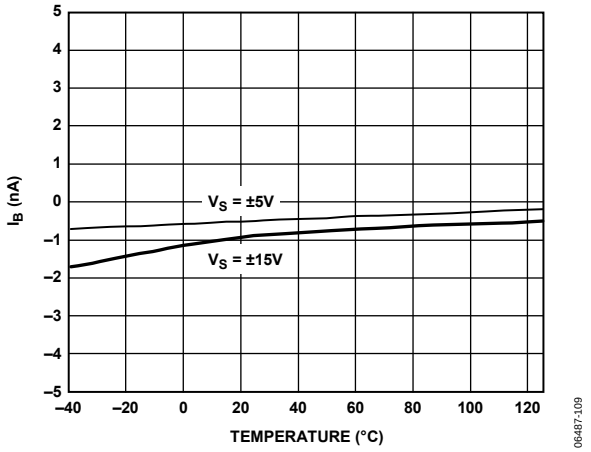

Figure 9. Input Bias Current vs. Temperature

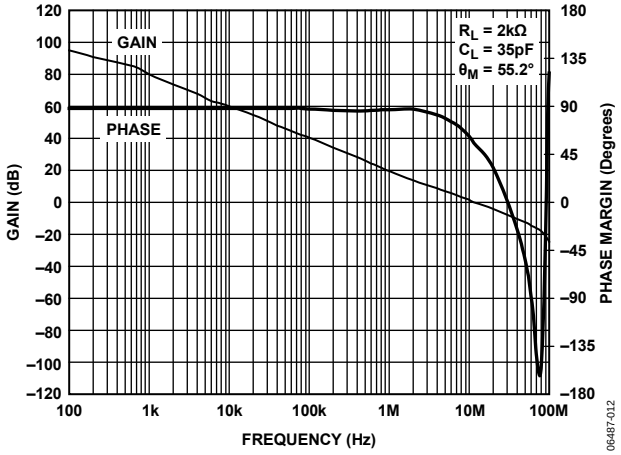

Figure 12. Gain and Phase vs. Frequency

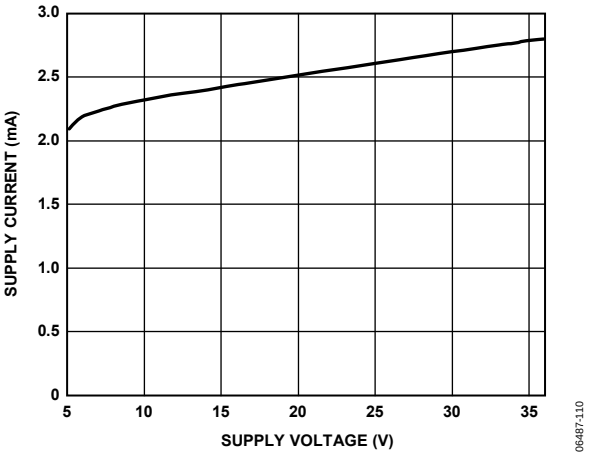

Figure 10. Supply Current vs. Total Supply Voltage

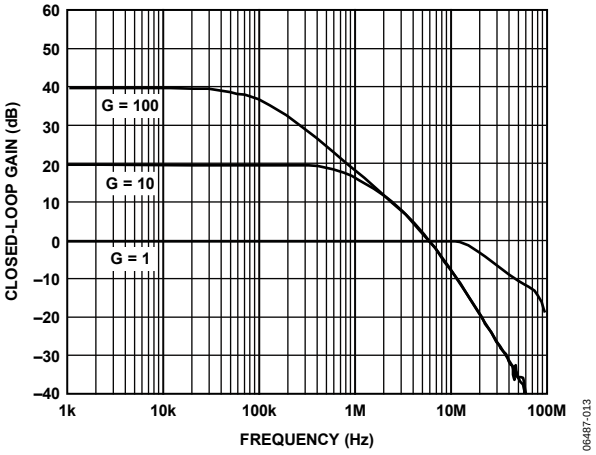

Figure 13. Closed-Loop Gain vs. Frequency

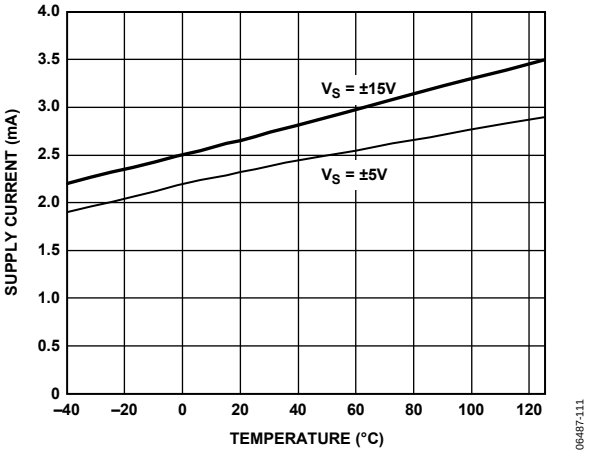

Figure 11. Supply Current vs. Temperature

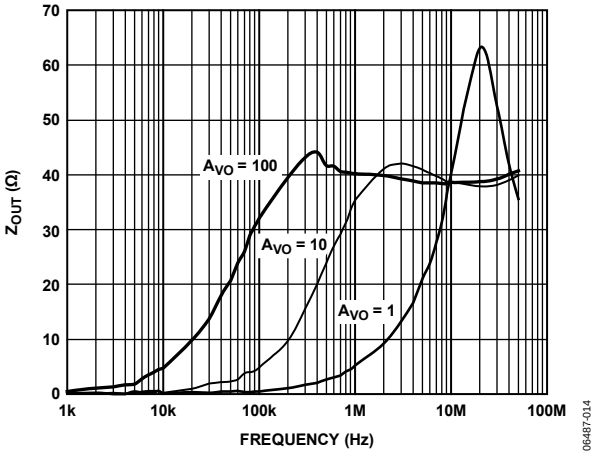

Figure 14. Z_{OUT} vs. Frequency

±15 V and ±5 V, T_A = 25°C, unless otherwise specified.

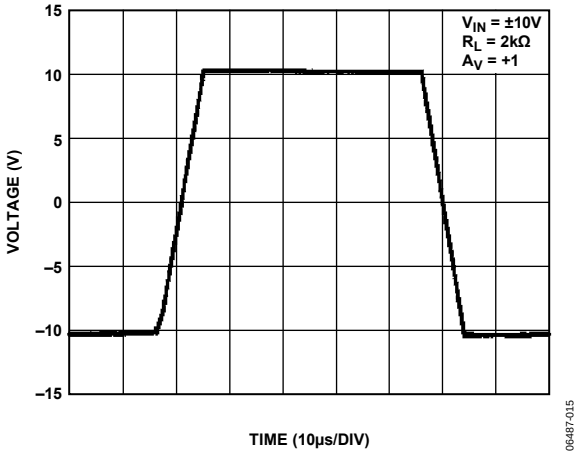

Figure 15. Large Signal Transient Response, V_{SY} = ±15 V

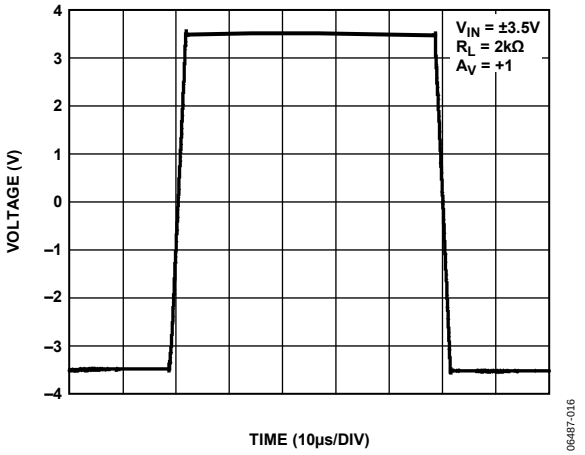

Figure 16. Large Signal Transient Response, V_{SY} = ±5 V

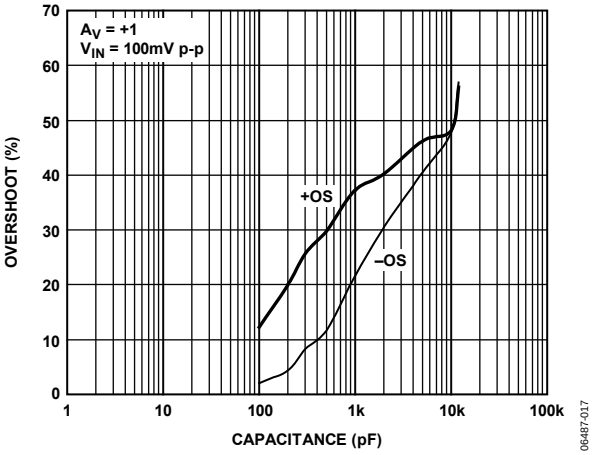

Figure 17. Small Signal Overshoot vs. Load Capacitance

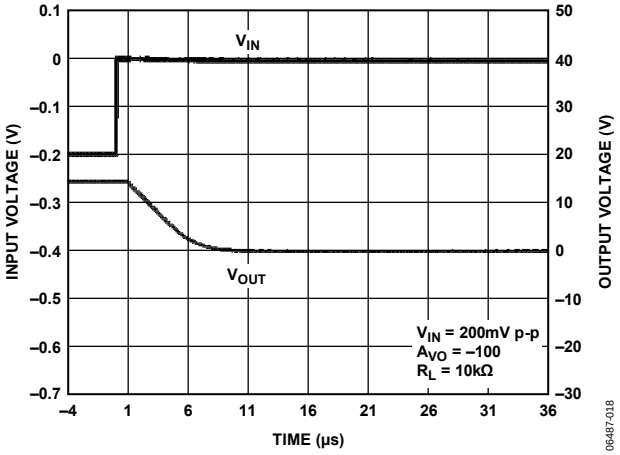

Figure 18. Positive Overvoltage Recovery

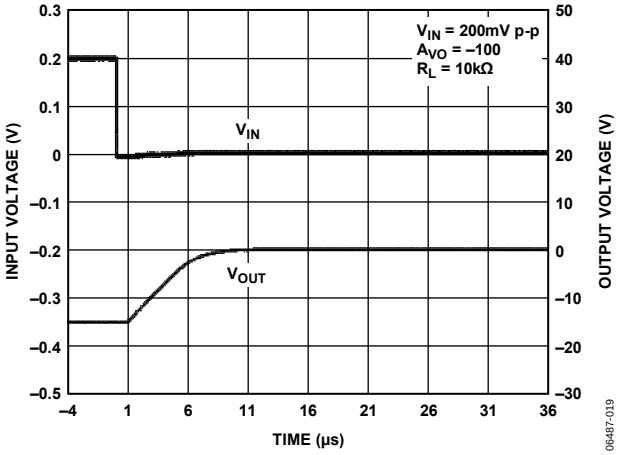

Figure 19. Negative Overvoltage Recovery

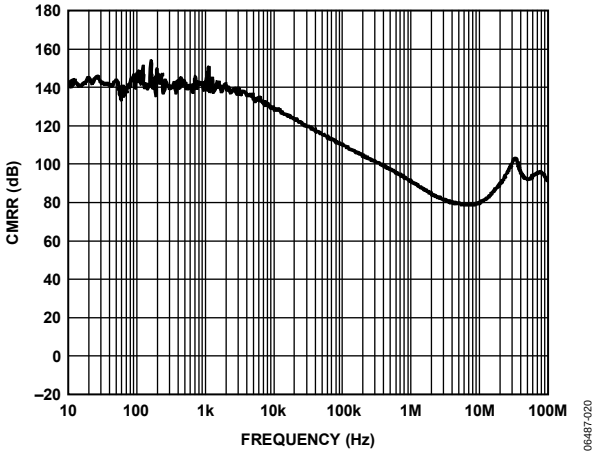

Figure 20. CMRR vs. Frequency

±15 V and ±5 V, T_A = 25°C, unless otherwise specified.

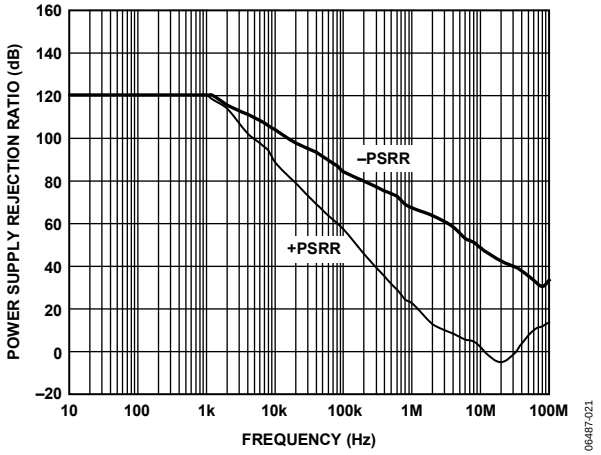

Figure 21. Power Supply Rejection Ratio vs. Frequency

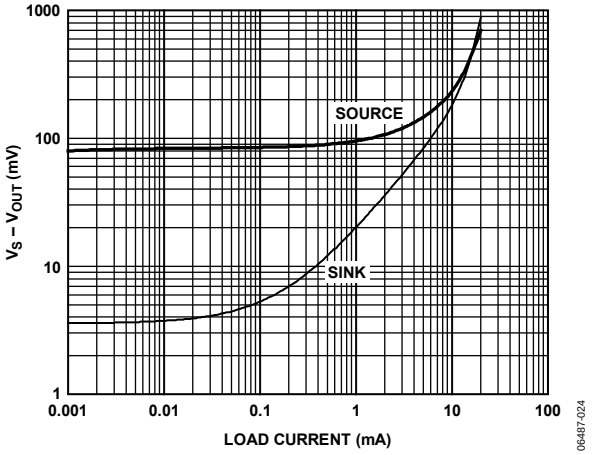

Figure 24. Output Saturation Voltage vs. Output Load Current

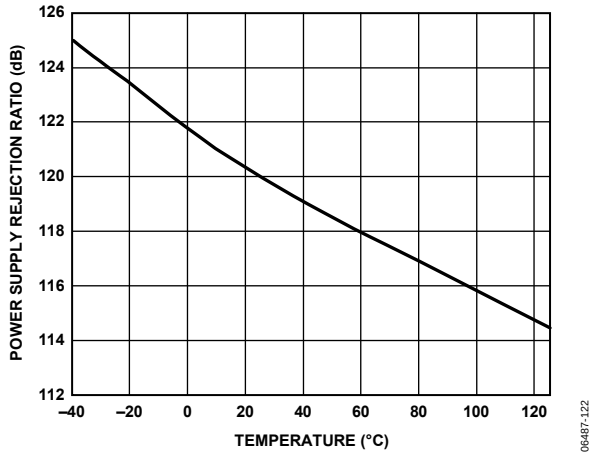

Figure 22. Power Supply Rejection Ratio vs. Temperature

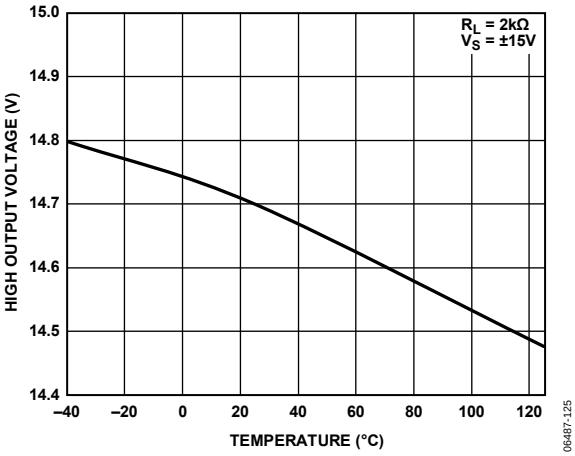

Figure 25. High Output Voltage, V_{OH} vs. Temperature, V_S = ±15 V

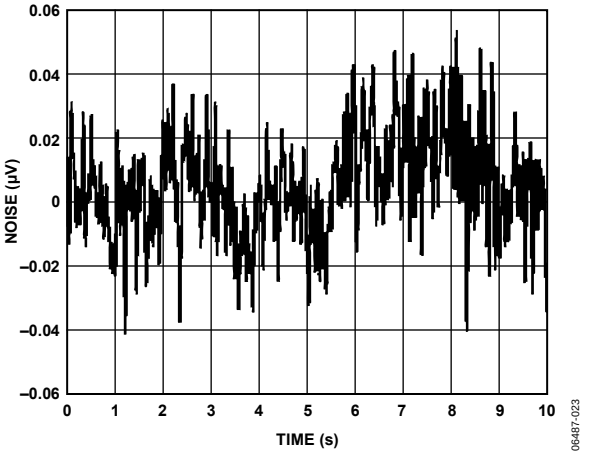

Figure 23. Voltage Noise (0.1 Hz to 10 Hz)

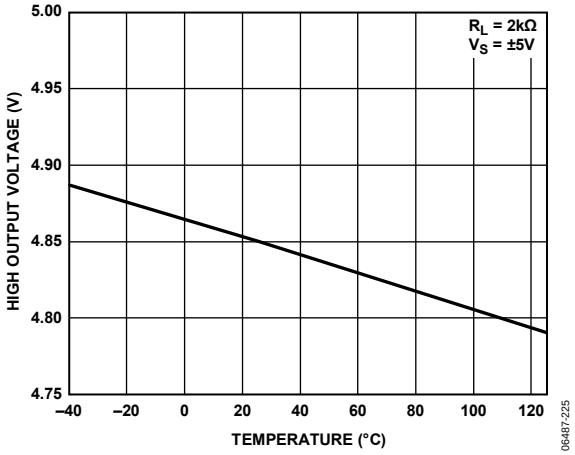

Figure 26. High Output Voltage, V_{OH} vs. Temperature, V_S = ±5 V

±15 V and ±5 V, T_A = 25°C, unless otherwise specified.

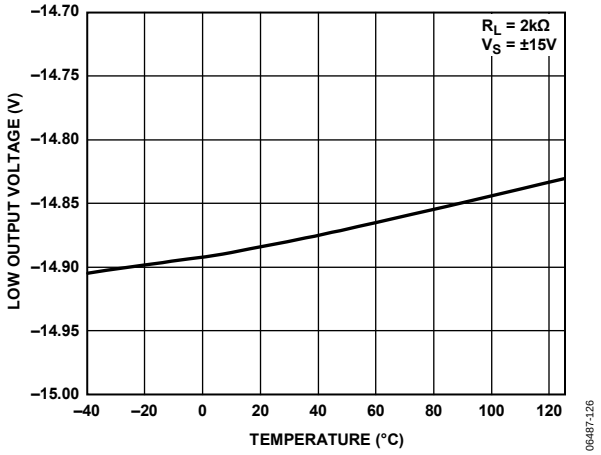

Figure 27. Low Output Voltage, V_{OL} vs. Temperature, V_S = ±15 V

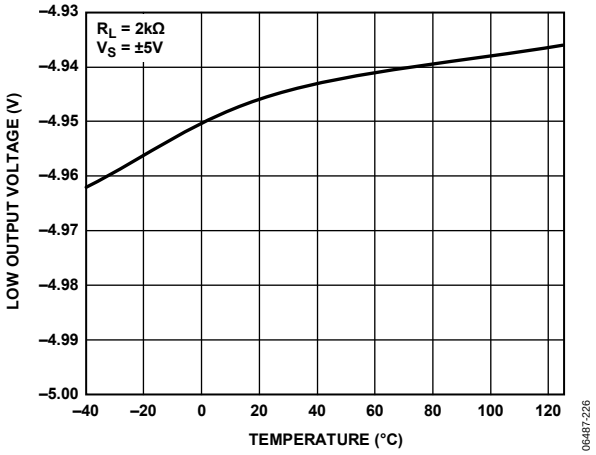

Figure 28. Low Output Voltage, V_{OL} vs. Temperature, V_S = ±5 V

OUTLINE DIMENSIONS

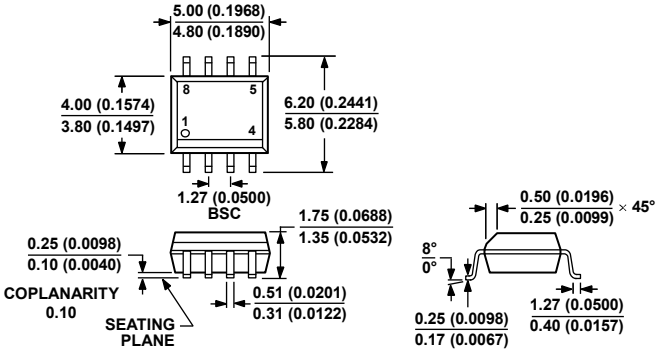

Figure 29. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body (R-8)
Dimensions shown in millimeters and (inches)

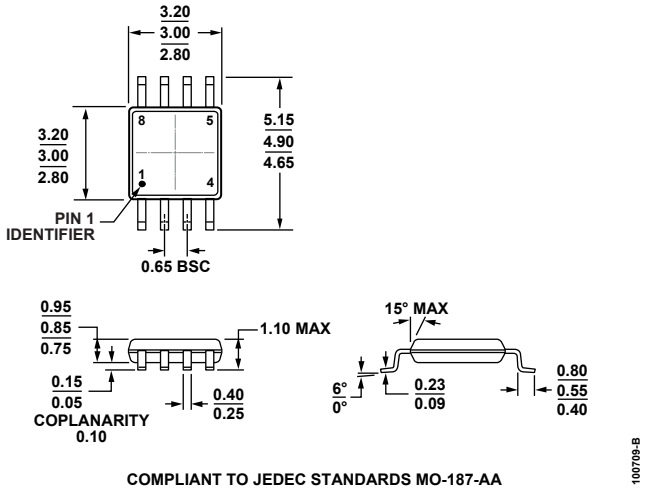

Figure 30. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option	Branding
AD8676ARMZ	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A13
AD8676ARMZ-REEL	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A13
AD8676ARZ	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8676ARZ-REEL	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8676ARZ-REEL7	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8676BRMZ	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A1L
AD8676BRMZ-REEL	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A1L
AD8676BRZ	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8676BRZ-REEL	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8676BRZ-REEL7	−40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	

[1] Z = RoHs Compliant Part.

NOTES

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